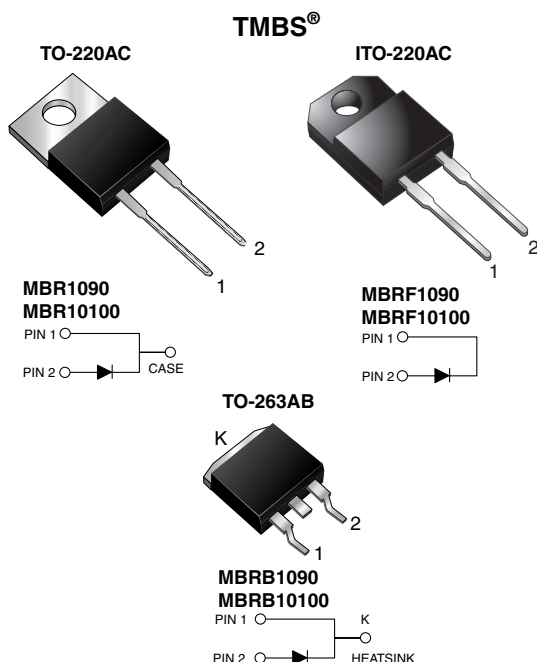




MBR(F,B)1090 & MBR(F,B)10100

Vishay General Semiconductor

High-Voltage Schottky Rectifier



FEATURES

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AC and ITO-220AC package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC



RoHS
COMPLIANT

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AC, ITO-220AC, TO-263AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	10 A
V_{RRM}	90 V, 100 V
I_{FSM}	150 A
V_F	0.65 V
$T_J \text{ max.}$	150 °C

MAXIMUM RATINGS ($T_C = 25$ °C unless otherwise noted)

PARAMETER	SYMBOL	MBR1090	MBR10100	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	90	100	V
Working peak reverse voltage	V_{RWM}	90	100	V
Maximum DC blocking voltage	V_{DC}	90	100	V
Maximum average forward rectified current at $T_C = 133$ °C	$I_{F(AV)}$	10		A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I_{FSM}	150		A
Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 60$ mH	E_{AS}	130		mJ
Peak repetitive reverse current at $t_p = 2$ μ s, 1 kHz, $T_J = 38$ °C $\pm$ 2 °C	I_{RRM}	0.5		A
Voltage rate of change (rated V_R)	dV/dt	10 000		V/ μ s
Isolation voltage (ITO-220AC only) From terminal to heatsink $t = 1$ min	V_{AC}	1500		V
Operating junction and storage temperature range	T_J, T_{STG}	- 65 to + 150		°C

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**ELECTRICAL CHARACTERISTICS** ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Maximum instantaneous forward voltage ⁽¹⁾	$I_F = 10\text{ A}$	V_F	0.80	V
	$T_C = 25\text{ }^{\circ}\text{C}$		0.65	
	$T_C = 125\text{ }^{\circ}\text{C}$		0.75	
Maximum reverse current at working peak reverse voltage ⁽²⁾	$I_F = 10\text{ A}$	I_R	100	μA
	$I_F = 20\text{ A}$		6.0	
	$T_J = 25\text{ }^{\circ}\text{C}$			
	$T_J = 100\text{ }^{\circ}\text{C}$			

Notes⁽¹⁾ Pulse test: 300 μs pulse width, 1 % duty cycle⁽²⁾ Pulse test: Pulse width $\leq 40\text{ ms}$ **THERMAL CHARACTERISTICS** ($T_C = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance	$R_{\theta JA}$	60	-	60	$^{\circ}\text{C/W}$
	$R_{\theta JC}$	2.0	3.5	2.0	

ORDERING INFORMATION (Example)

PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
TO-220AC	MBR10100-E3/4W	1.845	4W	50/tube	Tube
ITO-220AC	MBRF10100-E3/4W	1.661	4W	50/tube	Tube
TO-263AB	MBRB10100-E3/4W	1.384	4W	50/tube	Tube
TO-263AB	MBRB10100-E3/8W	1.384	8W	800/reel	Tape and reel

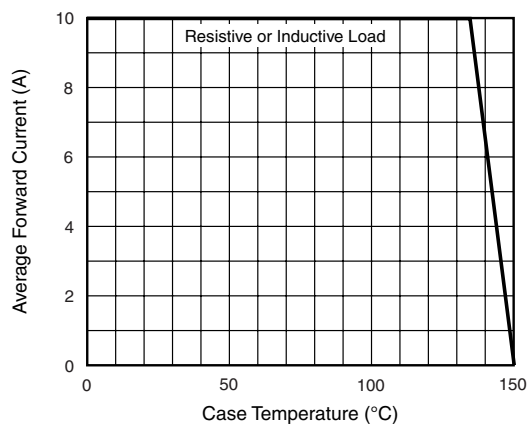
RATINGS AND CHARACTERISTICS CURVES $(T_A = 25\text{ }^{\circ}\text{C}$ unless otherwise noted)

Figure 1. Forward Current Derating Curve

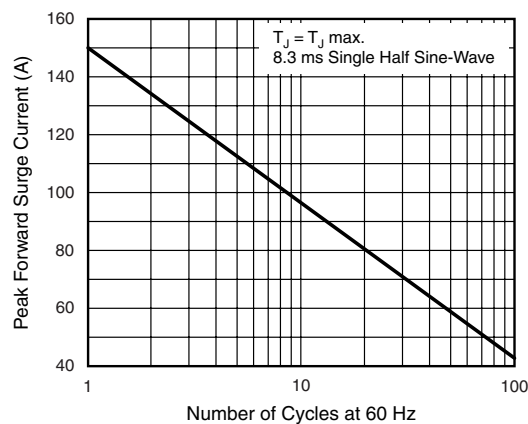


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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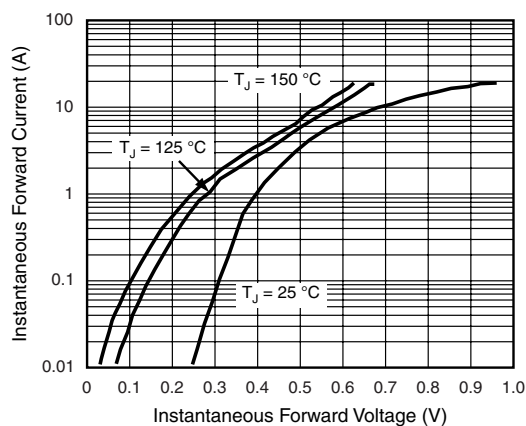


Figure 3. Typical Instantaneous Forward Characteristics

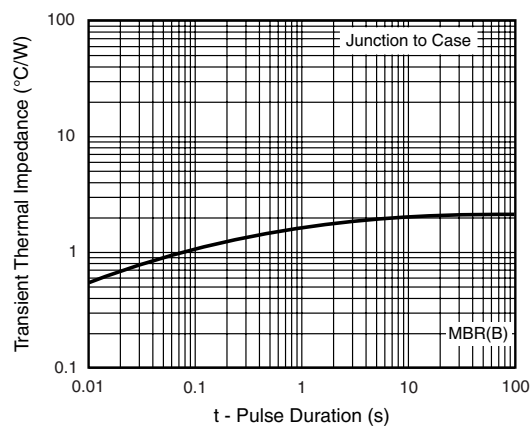


Figure 6. Typical Transient Thermal Impedance

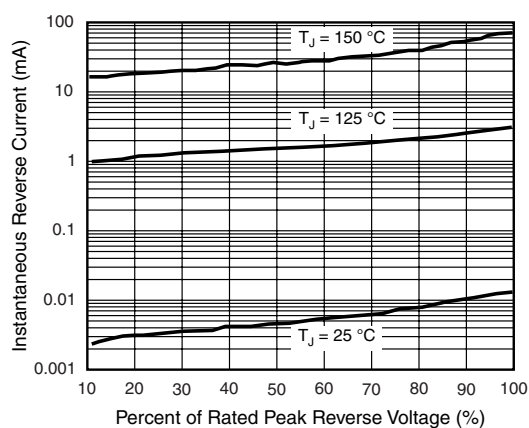


Figure 4. Typical Reverse Characteristics

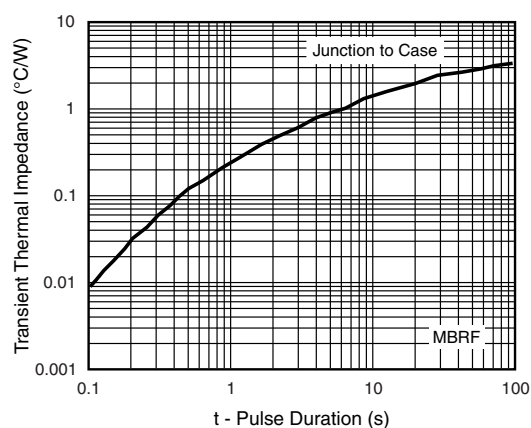


Figure 7. Typical Transient Thermal Impedance

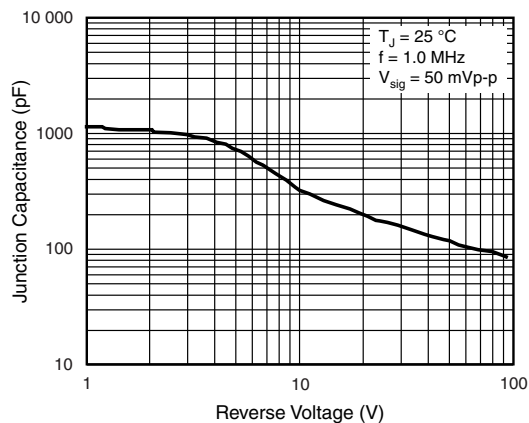


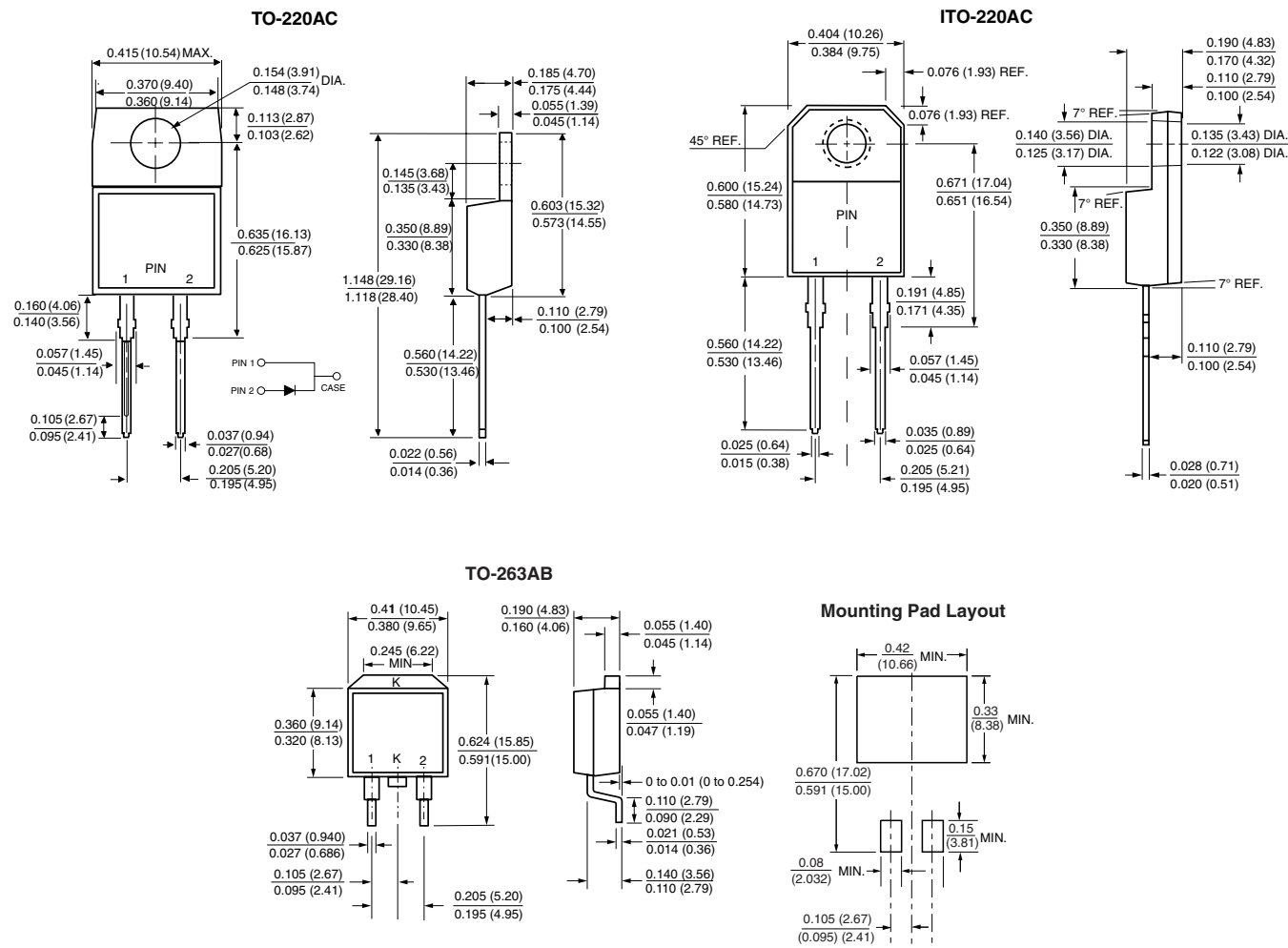
Figure 5. Typical Junction Capacitance

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9